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(54) **FIELD EMISSION DEVICE AND FIELD EMISSION DISPLAY**

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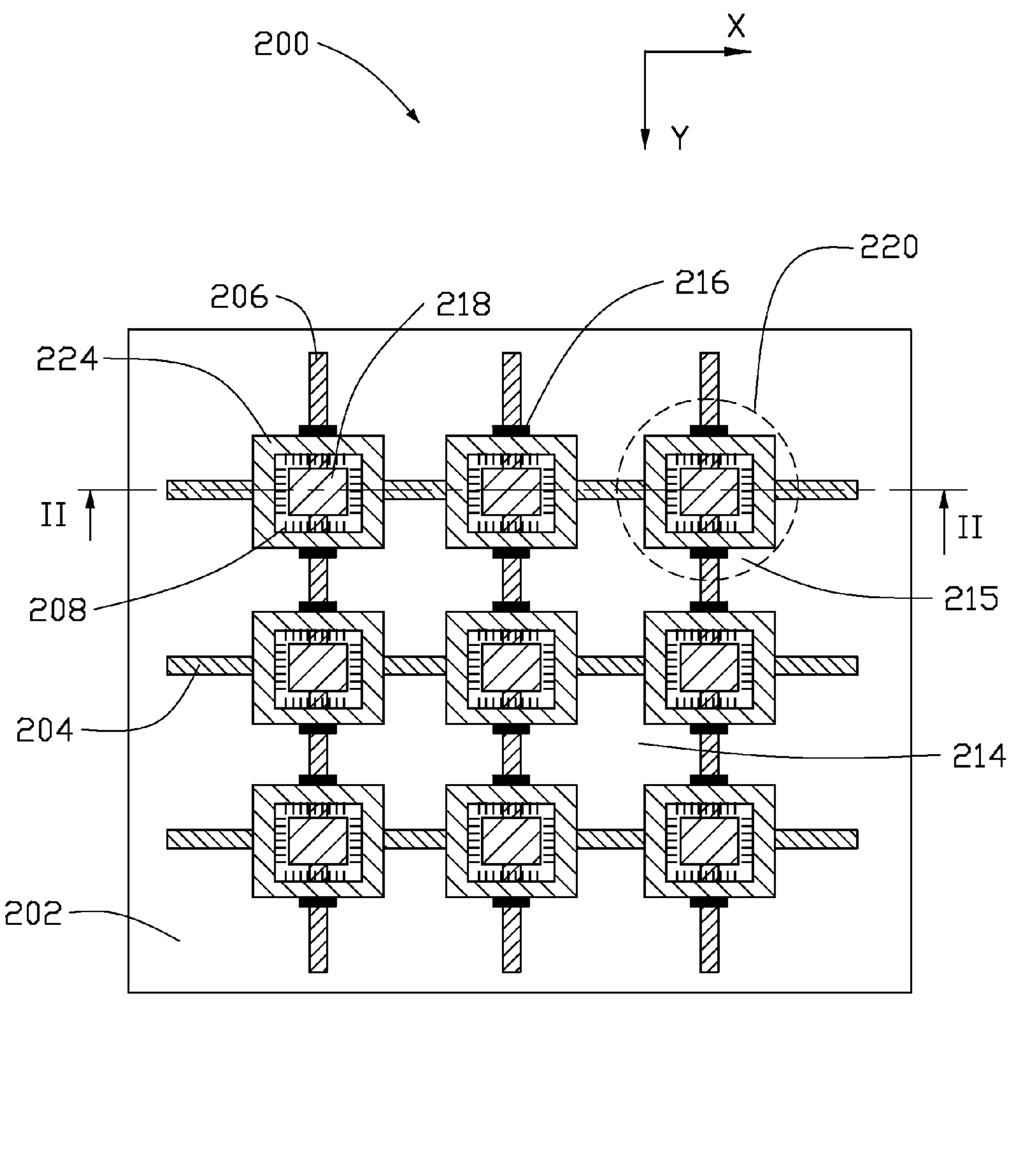
(57) **ABSTRACT**

A field emission display includes an insulating substrate, a number of first electrode down-leads, a number of second electrode down-leads, and a number of electron emission units. The first electrode down-leads are set an angle relative to the second electrode down-leads to define a number of cells and a number of intersections. Each electron emission unit is located at one of the plurality of intersections and in at least two adjacent cells. The electron emission unit includes a first electrode, a second electrode, and a plurality of electron emitters. The second electrode extends surrounding the first electrode. The plurality of electron emitters located on and electrically connected to at least one of the first electrode and the second electrode. A field emission display is also provided.



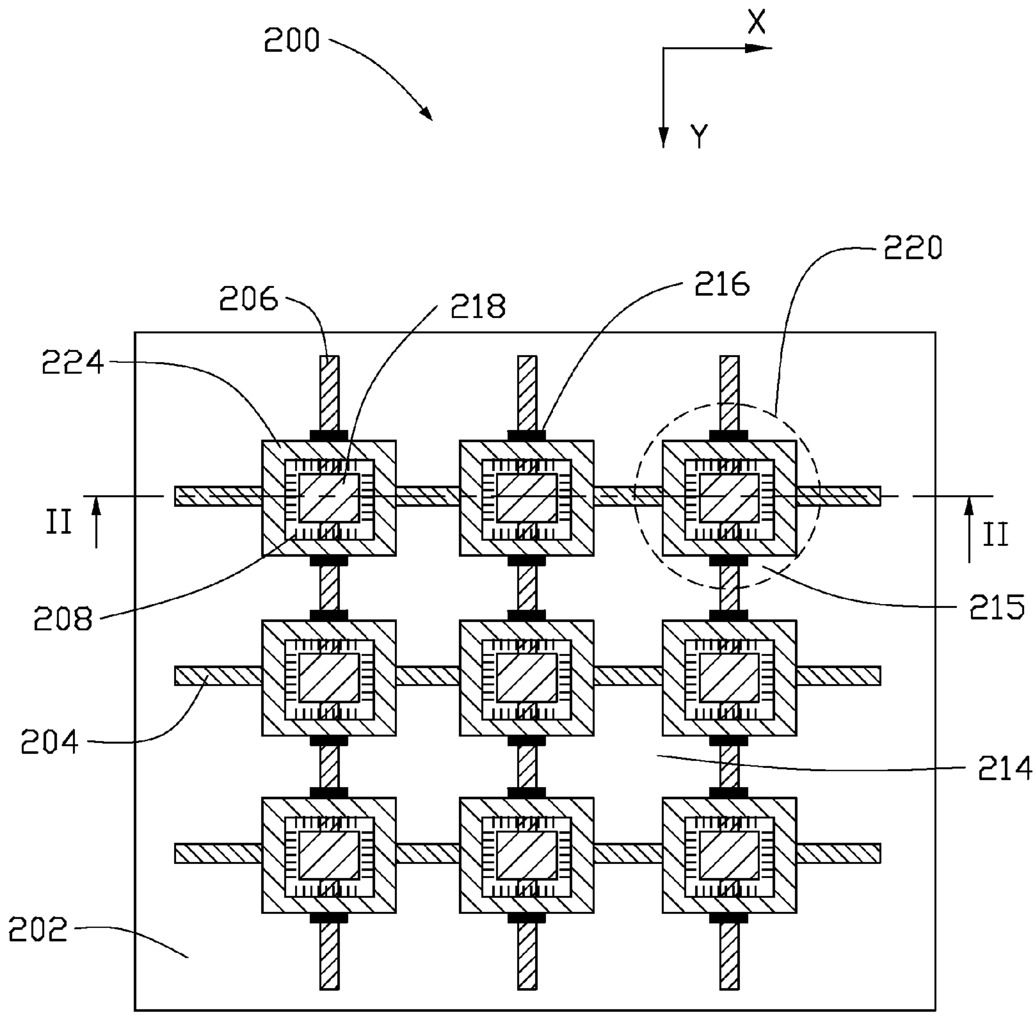


FIG. 1

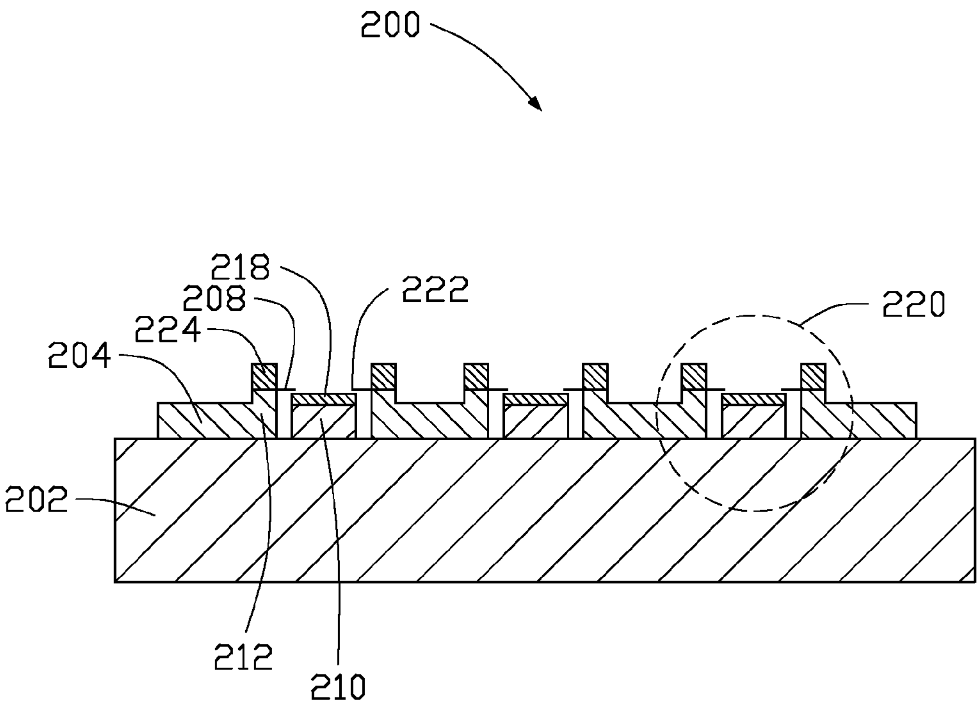


FIG. 2

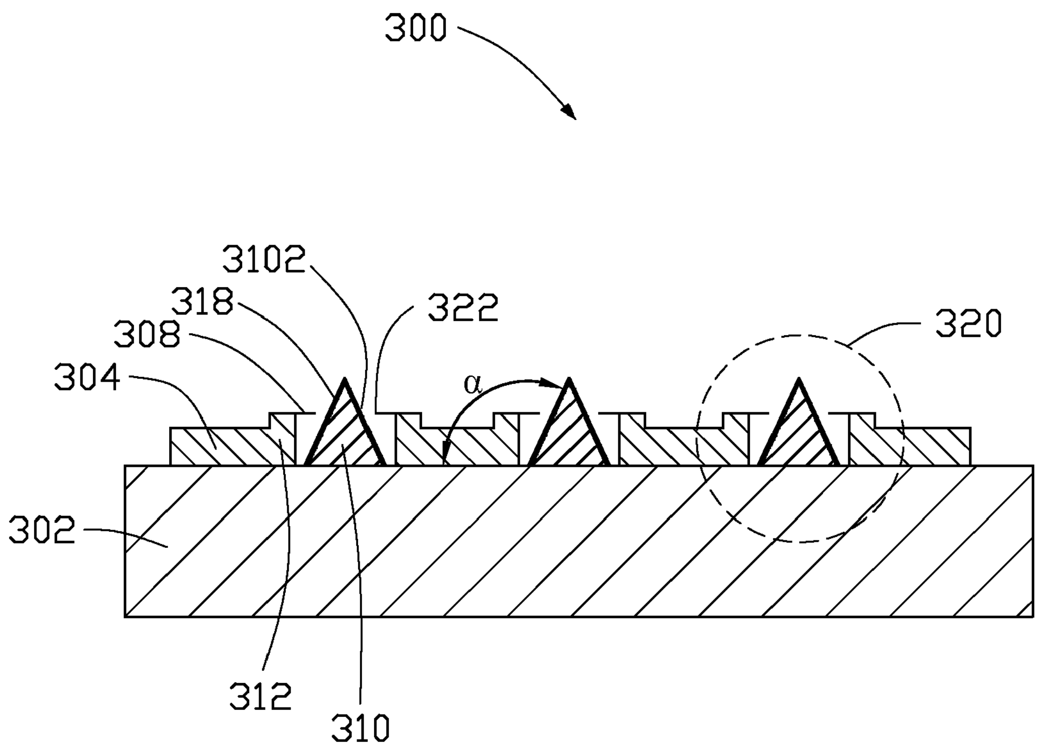


FIG. 3

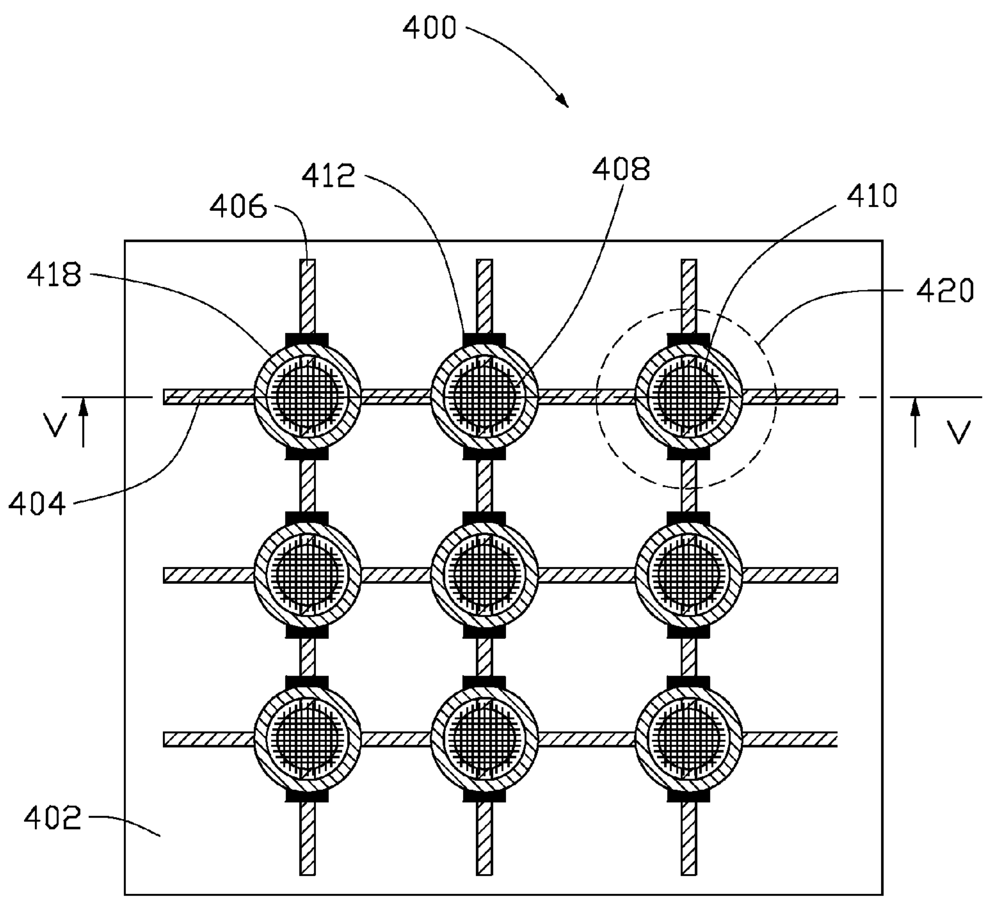


FIG. 4

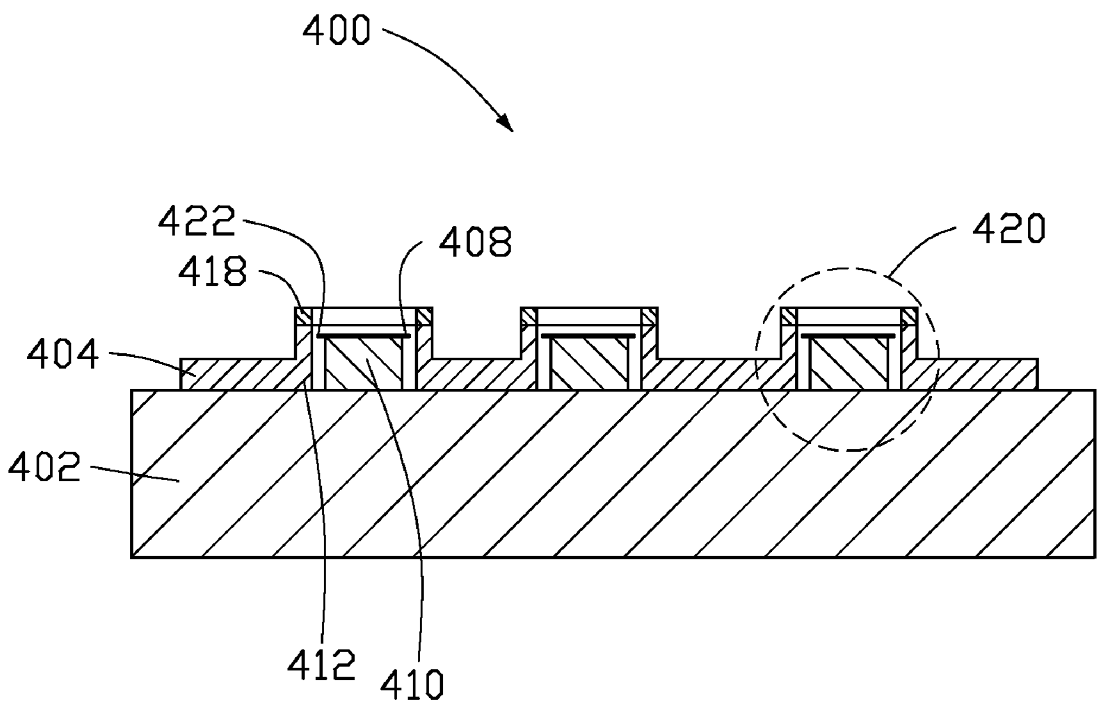


FIG. 5

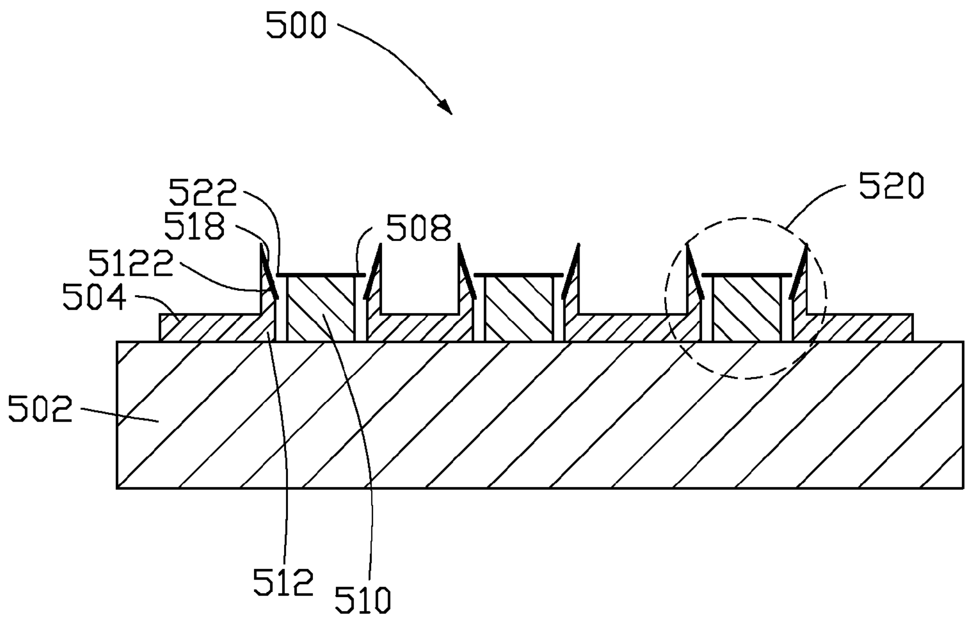


FIG. 6

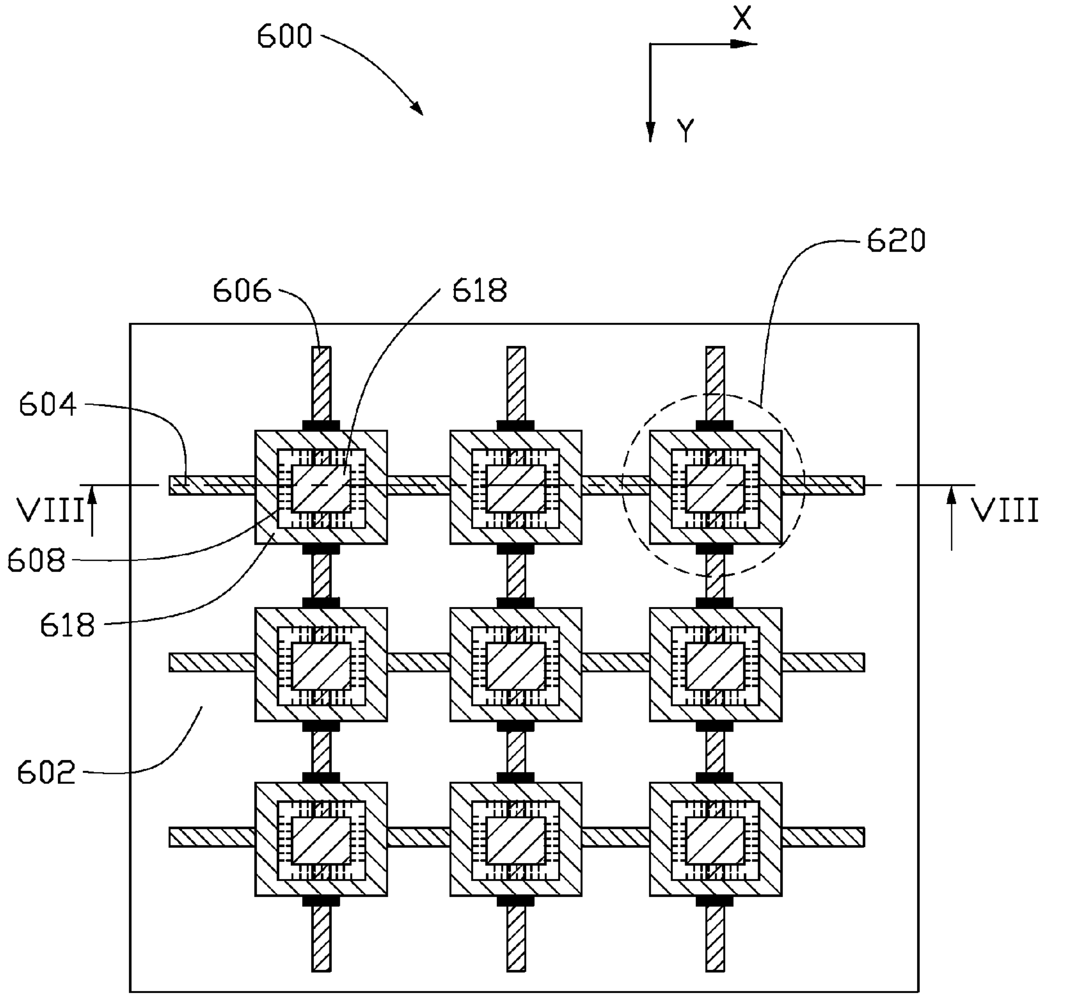


FIG. 7

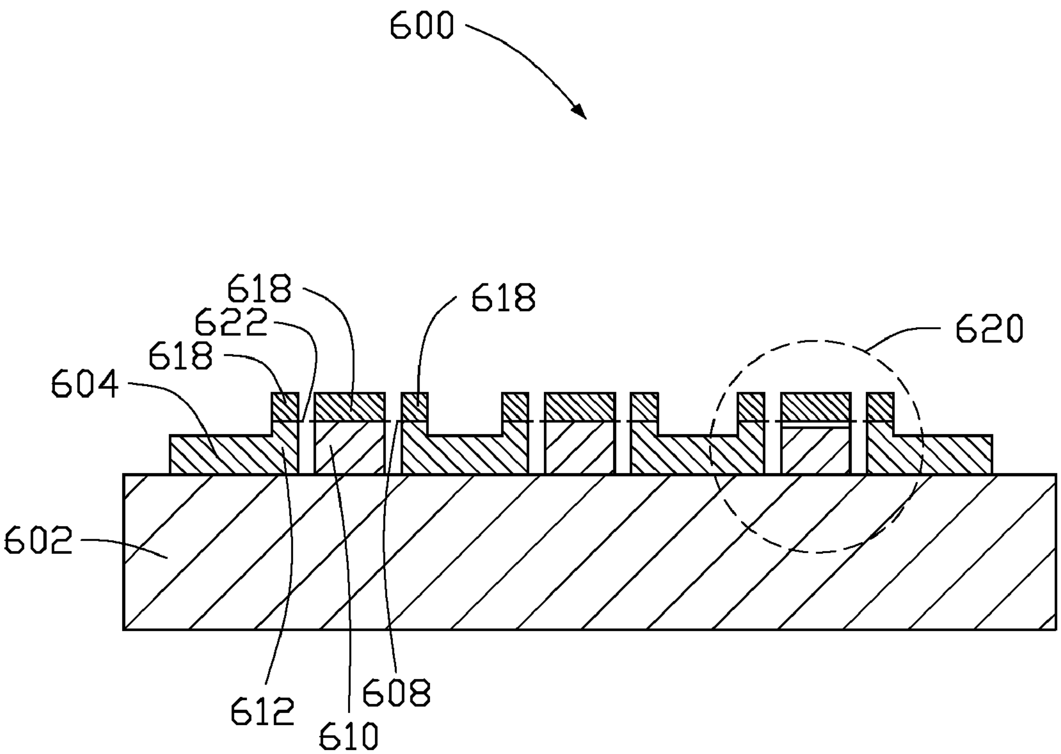


FIG. 8

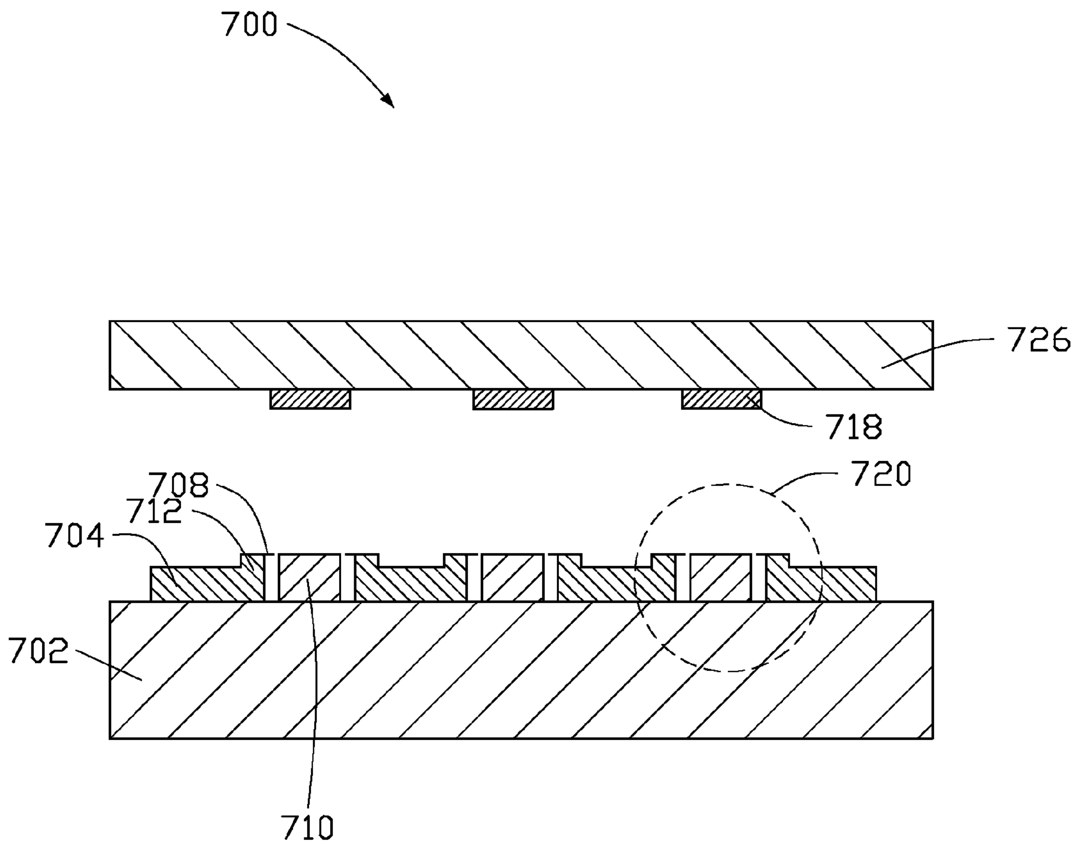


FIG. 9

FIELD EMISSION DEVICE AND FIELD EMISSION DISPLAY

CROSS-REFERENCE TO RELATED APPLICATIONS

[0001] This application claims all benefits accruing under 35 U.S.C. §119 from China Patent Application No. 201010612655.6, filed on Dec. 29, 2010 in the China Intellectual Property Office, disclosure of which is incorporated herein by reference. This application is related to applications entitled, "FIELD EMISSION DISPLAY", filed **** (Atty. Docket No. US38002); and "FIELD EMISSION DEVICE AND FIELD EMISSION DISPLAY", filed **** (Atty. Docket No. US38003).

BACKGROUND

[0002] 1. Technical Field

[0003] The present disclosure relates to a field emission device and a field emission display.

[0004] 2. Description of Related Art

[0005] Field emission displays (FED) can emit electrons under the principle of a quantum tunnel effect opposite to a thermal excitation effect, which is of great interest from the viewpoints of low power consumption.

[0006] A field emission display, according to the prior art usually includes a transparent plate, an insulating substrate opposite to the transparent plate, a number of supporters, and one or more cells located on the insulating substrate. Each cell includes a pixel unit. The pixel unit includes a rectangular first electrode, a rectangular second electrode spaced from and parallel to the first electrode, at least one electron emitter connected to the first electrode, and a phosphor layer located on the second electrode. However, the brightness of the field emission display is relatively low.

[0007] What is needed, therefore, is to provide a field emission display having relatively high brightness.

BRIEF DESCRIPTION OF THE DRAWINGS

[0008] Many aspects of the embodiments can be better understood with reference to the following drawings. The components in the drawings are not necessarily drawn to scale, the emphasis instead being placed upon clearly illustrating the principles of the embodiments. Moreover, in the drawings, like reference numerals designate corresponding parts throughout the several views.

[0009] FIG. **1** is a schematic, top view of one embodiment of a field emission display.

[0010] FIG. **2** is a schematic, cross-sectional view, along a line II-II of FIG. **1**.

[0011] FIG. **3** is a schematic, cross-sectional view of one embodiment of a field emission display.

[0012] FIG. **4** is a schematic, top view of one embodiment of a field emission display.

[0013] FIG. **5** is a schematic, cross-sectional view, along a line V-V of FIG. **4**.

[0014] FIG. **6** is a schematic, cross-sectional view of one embodiment of a field emission display.

[0015] FIG. **7** is a schematic, top view of another embodiment of a field emission display.

[0016] FIG. **8** is a schematic, cross-sectional view, along a line VIII-VIII of FIG. **7**.

[0017] FIG. **9** is a schematic, cross-sectional view of one embodiment of a field emission display.

DETAILED DESCRIPTION

[0018] The disclosure is illustrated by way of example and not by way of limitation in the figures of the accompanying drawings in which like references indicate similar elements. It should be noted that references to "an" or "one" embodiment in this disclosure are not necessarily to the same embodiment, and such references mean at least one.

[0019] References will now be made to the drawings to describe, in detail, various embodiments of the present field emission device and field emission display.

[0020] Referring to FIGS. **1** and **2**, a field emission display **200** of one embodiment includes an insulating substrate **202**, a number of substantially parallel first electrode down-leads **204**, a number of substantially parallel second electrode down-leads **206**, and a number of pixel units **220** arranged to form an array.

[0021] The first electrode down-leads **204** and the second electrode down-leads **206** are located on the insulating substrate **202**. The first electrode down-leads **204** are generally set at an angle to the second electrode down-leads **206** to form a grid and define a number of cells **214** and intersections **215**. A cell **214** is defined by two substantially adjacent first electrode down-leads **204** and two substantially adjacent second electrode down-leads **206** of the grid. Any one of the first electrode down-leads **204** and any one of the second electrode down-leads **206** can define an intersection **215**. The first electrode down-leads **204** and the second electrode down-leads **206** are electrically insulated at the intersections **215**. In FIG. **1**, the first electrode down-leads **204** are broken at the intersections **215**. Each of the pixel units **220** is located at one of the intersections **215**. In FIG. **1**, the lengthwise direction of the first electrode down-leads **204** is defined as an X direction, and the lengthwise direction of the second electrode down-leads **206** is defined as a Y direction.

[0022] The insulating substrate **202** is configured for supporting the first electrode down-leads **204**, the second electrode down-leads **206**, and the pixel units **220**. The shape, size, and thickness of the insulating substrate **202** can be chosen according to need. The insulating substrate **202** can be made of material such as ceramic, glass, resin, or quartz. In one embodiment, the insulating substrate **202** is a square glass substrate with a thickness of about 1 millimeter and an edge length of about 1 centimeter.

[0023] The first electrode down-leads **204** are located equidistantly apart. A distance between two adjacent first electrode down-leads **204** can range from about 50 micrometers to about 2 centimeters. The second electrode down-leads **206** are located equidistantly apart. A distance between adjacent two second electrode down-leads **206** can range from about 50 micrometers to about 2 centimeters. A suitable orientation of the first electrode down-leads **204** and the second electrode down-leads **206** are set at an angle with respect to each other. The angle can range from about 10 degrees to about 90 degrees. In one embodiment, the angle is 90 degrees, and the cell **214** is a square area.

[0024] The first electrode down-leads **204** and the second electrode down-leads **206** are made of conductive material such as metal or conductive slurry. In one embodiment, the first electrode down-leads **204** and the second electrode down-leads **206** are formed by applying conductive slurry on the insulating substrate **202** using screen printing process, the conductive slurry being composed of metal powder, glass powder, and binder. The metal powder can be silver powder, the glass powder has a low melting point, and the binder can be terpineol or ethyl cellulose (EC). The conductive slurry can include about 50% to about 90% (by weight) of the metal powder, about 2% to about 10% (by weight) of the glass powder, and about 8% to about 40% (by weight) of the binder. In one embodiment, each of the first electrode down-leads **204** and the second electrode down-leads **206** is formed with a width in a range from about 30 micrometers to about 100 micrometers and with a thickness in a range from about 10 micrometers to about 50 micrometers. However, it is noted that dimensions of each of the first electrode down-leads **204** and the second electrode down-leads **206** can vary corresponding to the dimension of each cell **214**.

[0025] The pixel unit **220** includes a first electrode **212**, a second electrode **210**, an electron emitter **208**, and a phosphor layer **218**. The first electrode **212** and the second electrode **210** are located on the insulating substrate **202** and spaced from each other. At least part of the first electrode **212** extends surrounding the second electrode **210**. The first electrode **212** can be L-shaped, U-shaped, C-shaped, semicircular-shaped or ring-shaped. The pixel unit **220** can be located at one of the intersections **215** and in at least two adjacent cells **214**. In FIG. **1**, each pixel unit **220** is located in four adjacent cells **214**. The second electrodes **210** and the first electrode down-leads **204** are spaced from each other. A plurality of insulators **216** is sandwiched between the first electrodes **212** and the second electrode down-leads **206** to avoid short-circuiting. The insulators **216** are located at every intersection of the first electrode **212** and the second electrode down-leads **206** for providing electrical insulation. In one embodiment, the insulator **216** is a dielectric insulator.

[0026] The first electrode **212** is used as a cathode electrode and electrically connected to the first electrode down-lead **204**. The second electrode **210** is used as an anode electrode and electrically connected to the second electrode down-lead **206**. The electron emitter **208** is located between the first electrode **212** and the second electrode **210**, and extends from the first electrode **212** toward the second electrode **210**. In one embodiment, one end of the electron emitter **208** is electrically connected to the first electrode **212**, and the other end of the electron emitter **208** points to the second electrode **210** and is used as an electron emission portion **222**. The electron emission portion **222** is spaced from the second electrode **210**. The electron emitter **208** is suspended above the insulating substrate **202**. The phosphor layer **218** is located on a surface of the second electrode **210**. The electrons emitted from the electron emitter **208** can bombard the phosphor layer **218** to light.

[0027] The second electrode **210** is a conductor such as a metal layer, ITO layer, or conductive slurry layer. In one embodiment, the second electrode **210** and the second electrode down-lead **206** are made by printing conductive slurry at the same time. The second electrode **210** can be a planar conductor. The size and shape of the second electrode **210** can be selected according to the size of the cell **214**. In one embodiment, the second electrode **210** is a square planar conductor with a side length of about 30 micrometers to about 15 millimeters and a thickness of about 10 micrometers to about 500 micrometers. In one embodiment, the second electrode **210** is a square planar conductor with a side length of about 100 micrometers to about 700 micrometers and a thickness of about 20 micrometers to about 100 micrometers.

[0028] The first electrode **212** is a conductor such as a metal layer, ITO layer, or conductive slurry layer. In one embodiment, the first electrode **212** and the first electrode down-lead **204** are made by printing conductive slurry at the same time. The first electrode **212** can be a planar conductor with a rectangular cross section. The size and shape of first electrode **212** can be selected according to the size and shape of the second electrode **210**. In one embodiment, the first electrode **212** is a square frame around the second electrode **210**. The first electrodes **212** can have a width in a range from about 30 micrometers to 1000 micrometers and a thickness in a range from about 10 micrometers to about 500 micrometers. The thickness of the first electrode **212** can be greater than the thickness of the second electrode **210** so that the electromagnetic interference between the adjacent pixel units **220** can be prevented.

[0029] The phosphor layer **218** is located on the top surface of the second electrode **210**. The phosphor layer has the same shape as that of the second electrode **210**. The phosphor layer **218** can be white phosphor layer, red phosphor layer, green phosphor layer, or blue phosphor layer. The phosphor layer **218** can be formed by printing, coating, or depositing. The thickness of the phosphor layer **218** can be selected according to need. In one embodiment, the thickness of the phosphor layer **218** is in a range from about 5 micrometers to about 50 micrometers.

[0030] The electron emitter **208** is located on the first electrode **212**. The electron emitter **208** can be linear emitter such as silicon wires, carbon nanotubes, carbon fibers or carbon nanotube wires. The lengthwise direction of the electron emitter **208** can be parallel to the surface of the insulating substrate **202**. The electron emission portion **222** of the electron emitter **208** points to the second electrode **210** and spaced from the second electrode **210** by a distance in a range from about 2 micrometers to about 500 micrometers. In one embodiment, the distance between the electron emission portion **222** and the second electrode **210** is in a range from about 50 micrometers to about 300 micrometers. In one embodiment, the electron emission portion **222** can extend above the phosphor layer **218**.

[0031] In one embodiment, the electron emitter **208** includes a number of carbon nanotube wires located in at least two cells **214**, and evenly spaced from and in parallel with each other. All the carbon nanotube wires can be arranged to form L-shaped, U-shaped, C-shaped, semicircular-shaped or ring-shaped to surround the second electrode **210** or locate on at least two opposite sides of the second electrode **210**. The length of the carbon nanotube wires can be in a range from about 10 micrometers to about 1 centimeter. The distance between each two adjacent carbon nanotube wires can be in a range from about 10 micrometers to about 500 micrometers. One end of the carbon nanotube wire is fixed on the first electrode **212** by a fixing electrode **224** or conductive adhesive (not shown). The carbon nanotube wire can be a substantially pure structure of the carbon nanotubes, with few impurities. The carbon nanotube wire is a free standing structure.

[0032] The carbon nanotube wire includes a plurality of successive carbon nanotubes joined end to end by van der Waals attractive force therebetween. The carbon nanotubes in the carbon nanotube wire can be single-walled, double-walled, or multi-walled carbon nanotubes. The carbon nanotube wire can be untwisted or twisted. The untwisted carbon nanotube wire includes a plurality of carbon nanotubes substantially oriented along a same direction (i.e., a direction along the length of the untwisted carbon nanotube wire). The carbon nanotubes are parallel to the axis of the untwisted carbon nanotube wire. The twisted carbon nanotube wire includes a plurality of carbon nanotubes helically oriented around an axial direction of the twisted carbon nanotube wire.

[0033] The electron emitter **208** can be formed by disposing and heating a carbon nanotube slurry layer or disposing and cutting a carbon nanotube film. The carbon nanotube slurry layer includes a number of carbon nanotubes, a glass powder, and an organic carrier. The organic carrier is volatilized during the heating process. The glass powder can be melted and solidified to form a glass layer to fix the carbon nanotubes on the first electrodes **212** during the heating and cooling process.

[0034] In one embodiment, the electron emitter **208** is made by the steps of:

[0035] step (a), providing two carbon nanotube films;

[0036] step (b), placing the two carbon nanotube films on the first electrode **212** and the second electrode **210** to cover all of the first electrodes **212** and the second electrodes **210**, wherein an angle between the aligned directions of the carbon nanotubes in the two adjacent carbon nanotube films is about 90°; and

[0037] step (c), breaking the two carbon nanotube films to form a number of carbon nanotube wires spaced from and parallel with each other.

[0038] In step (a), the carbon nanotube film can be drawn from a carbon nanotube array. Examples of carbon nanotube film are taught by U.S. Pat. No. 7,045,108 to Jiang et al., and WO 2007015710 to Zhang et al. The carbon nanotube film includes a plurality of successive and oriented carbon nanotubes joined end-to-end by van der Waals attractive force therebetween, and arranged along the same direction. The carbon nanotube film is a free-standing film. The term "free-standing film" means that the film can sustain the weight of itself when it is hoisted by a portion thereof without any significant damage to its structural integrity.

[0039] In step (b), the carbon nanotubes of the carbon nanotube film extend from the first electrode **212** to the second electrode **210**. If the first electrode **212** is ring-shaped, more than two carbon nanotube films can be stacked with each other. The angle between the aligned directions of the carbon nanotubes in the adjacent carbon nanotube films can range from about 0° to about 90°.

[0040] Furthermore, the carbon nanotube films are treated with a volatile organic solvent in step (b). The organic solvent is applied to soak the entire surface of the carbon nanotube film. During the soaking, adjacent parallel carbon nanotubes in the carbon nanotube film will bundle together, due to the surface tension of the organic solvent as it volatilizes, and thus, the carbon nanotube film will be shrunk into untwisted carbon nanotube wire. The organic solvent can be ethanol, methanol, acetone, dichloroethane, or chloroform.

[0041] In step (c), the carbon nanotube film can be cut by a laser beam, an electron beam, or can be broken by heat. In one embodiment, the carbon nanotube film is cut by a laser beam. The laser beam can be moved along the first electrode down-leads **204** and the second electrode down-leads **206** to remove the carbon nanotubes between the adjacent pixel units **220**. The laser beam can be moved around the second electrode **210** to break the carbon nanotubes between the first electrode **212** and the second electrode **210**. Also, the laser beam can be moved to remove the carbon nanotubes on the second electrode **210**. The power of the laser beam can be in a range from about 10 W to about 50 W. The scanning speed of the laser beam can be in a range from about 0.1 mm/sec to about 10,000 mm/sec. The width of the laser beam can be in a range from about 1 micrometer to about 400 micrometers.

[0042] Further the field emission display **200** can include a driving circuit (not shown) to drive the field emission display **200** to display. The driving circuit can control the pixel units **220** via the electrode down-leads **204**, **206** to display a dynamic image. The field emission display **200** can be used in a field of advertisement billboard, newspaper, or electronic book. In use, the field emission display **200** should be sealed in a vacuum.

[0043] Referring to FIG. **3**, a field emission display **300** of one embodiment includes an insulating substrate **302**, a number of substantially parallel first electrode down-leads **304**, a number of substantially parallel second electrode down-leads (not shown), and a number of pixel units **320**. The field emission display **300** is similar to the field emission display **200** except that the second electrode **310** has a bearing surface **3102** inclined to the insulating substrate **302**, and the phosphor layers **318** is located on the bearing surface **3102** and exposed to the electron emitter **308**.

[0044] The bearing surface **3102** can be flat or curved. If the bearing surface **3102** is flat, an angle α between the bearing surface **3102** and the surface of the insulating substrate **302** can be greater than 90 degrees and less than 180 degrees. In one embodiment, the angle α between the bearing surface **3102** and the surface of the insulating substrate **302** is in a range from about 120 degrees to about 150 degrees. If the bearing surface **3102** is curved, the bearing surface **3102** can be a convex surface or a concave surface. The bearing surface **3102** can intersect with the insulating substrate **302** or can be spaced from the insulating substrate **302**.

[0045] In one embodiment, the second electrode **310** is rectangular pyramid and has four flat bearing surfaces **3102** adjacent to and exposed to the electron emitter **308** around the second electrode **310**. Four phosphor layers **318** are located on the four bearing surfaces **3102** respectively and exposed to the electron emission portion **322**. Because the phosphor layers **318** are located on the bearing surface **3102** of the second electrode **310** so that the phosphor layer **318** has a relative larger area and bombarded easily by the electron emitted from the electron emitter **308**. Thus, the brightness of the field emission display **300** is improved.

[0046] The second electrode **310** can be formed by screen printing a number of stacked square conductive slurry layers repeatedly. The length side of the conductive slurry layer decreases gradually. Because of the high flowability of the conductive slurry, four inclines can be formed to be used as the bearing surface **3102**.

[0047] Referring to FIGS. **4** and **5**, a field emission display **400** of one embodiment includes an insulating substrate **402**, a number of substantially parallel first electrode down-leads **404**, a number of substantially parallel second electrode down-leads **406**, and a number of pixel units **420**. The field emission display **400** is similar to the field emission display **200** except that the first electrode **412** is ring-shaped and used as an anode electrode, the second electrode **410** is round and used as a cathode electrode, the electron emitters **408** are connected to the second electrode **410**, and the phosphor layer **418** is located on the first electrode **412**.

[0048] In one embodiment, the phosphor layer **418** is located on the first electrode **412** to form a ring around the second electrode **410**. The electron emitters **408** are located on a top surface of the second electrode **410**. The electron emitter **408** includes a number of electron emission portions

422 arranged to form a ring and pointing to the phosphor layer **418**. In one embodiment, the electron emitters **408** include a number of carbon nanotube wires crossed with each other and having two opposite ends extending to the first electrode **412**. Because the phosphor layer **418** is located on the first electrode **412** to form a ring around the second electrode **410**, and the electron emitter **408** includes a number of electron emission portions **422** arranged to form a ring and pointing to the phosphor layer **418**, the brightness and uniformity of the field emission display **400** is further improved.

[0049] Referring to FIG. **6**, a field emission display **500** of one embodiment includes an insulating substrate **502**, a number of substantially parallel first electrode down-leads **504**, a number of substantially parallel second electrode down-leads (not shown), and a number of pixel units **520**. The field emission display **500** is similar to the field emission display **400** except that the first electrode **512** has a bearing surface **5122** inclined to the insulating substrate **502**, and the phosphor layer **518** is located on the bearing surfaces **5122** of the first electrode **512**.

[0050] In one embodiment, the width of the first electrode **512** decreases along a direction away from the insulating substrate **502** so that the first electrode **512** has a bearing surface **5122** around and exposed to the electron emitter **508**. The electron emitter **508** includes a number of electron emission portions **522** arranged to form a ring and pointing to the phosphor layer **518** on the bearing surface **5122**. Because the first electrode **512** has bearing surfaces **5122** around and exposed to the electron emitter **508**, the phosphor layer **518** located on the bearing surfaces **5122** has a maximum area and is bombarded easily by the electron emitted from the electron emitter **508**. Thus, the brightness and uniformity of the field emission display **500** is further improved.

[0051] Referring to FIGS. **7** and **8**, a field emission display **600** of one embodiment includes an insulating substrate **602**, a number of substantially parallel first electrode down-leads **604**, a number of substantially parallel second electrode down-leads **606**, and a number of pixel units **620**. The field emission display **600** is similar to the field emission display **200** except that both the first electrode **612** and the second electrode **610** have the electron emitter **608** and the phosphor layer **618** located thereon.

[0052] In one embodiment, the electron emitter **608** includes a number of first carbon nanotube wires located on the first electrode **612** and a number of second carbon nanotube wires located on the second electrode **610**. Two phosphor layers **618** are located on the first electrode **612** and the second electrode **610** respectively to cover the electron emitter **608**. The carbon nanotube wires on the first electrode **612** extend to the second electrode **610** and have a number of electron emission portions **622** pointing to the phosphor layers **618** on the second electrode **610**. The carbon nanotube wires on the second electrode **610** extend to the first electrode **612** and have a number of electron emission portions **622** pointing to the phosphor layers **618** on the first electrode **612**. Both the first electrode **612** and the second electrode **610** can be used as an anode or cathode. In one embodiment, an alternating voltage can be supplied to the first electrode **612** and the second electrode **610** so the first electrode **612** and the second electrode **610** can be used as the anode and cathode alternately in the emission display **600**. Thus, the field emission display **600** can have an improved lifespan.

[0053] Referring to FIG. **9**, a field emission display **700** of one embodiment includes an insulating substrate **702**, a number of substantially parallel first electrode down-leads **704**, a number of substantially parallel second electrode down-leads (not shown), and a number of pixel units **720**. The field emission display **700** is similar to the field emission display **200** except that the field emission display **700** further includes a third electrode **726** spaced from and substantially parallel to the insulating substrate **702**, and the phosphor layer **718** is located on the third electrode **726** and exposed to the electron emitter **708**.

[0054] In one embodiment, a number of phosphor layers **718** are located on the third electrode **726**. Each of the phosphor layers **718** is located corresponding to one of the pixel units **720**. In use, the first electrode **712** is used as a cathode, the second electrode **710** is used as a gate, and the third electrode **726** is used as an anode. The electron emitter **708** can emit electrons under the electric field of the second electrode **710**. The electrons can move toward the third electrode **726** under the electric field of the third electrode **726** to bombard the phosphor layers **718** to light.

[0055] It is to be understood that the above-described embodiments are intended to illustrate rather than limit the disclosure. Any elements described in accordance with any embodiments is understood that they can be used in addition or substituted in other embodiments. Embodiments can also be used together. Variations may be made to the embodiments without departing from the spirit of the disclosure. The above-described embodiments illustrate the scope of the disclosure but do not restrict the scope of the disclosure.

[0056] Depending on the embodiment, certain of the steps of methods described may be removed, others may be added, and the sequence of steps may be altered. It is also to be understood that the description and the claims drawn to a method may include some indication in reference to certain steps. However, the indication used is only to be viewed for identification purposes and not as a suggestion as to an order for the steps.

What is claimed is:

1. A field emission device, comprising:

an insulating substrate;

a plurality of first electrode down-leads substantially parallel to each other and located on the insulating substrate;

a plurality of second electrode down-leads substantially parallel to each other and located on the insulating substrate, wherein the plurality of first electrode down-leads is set an angle relative to the plurality of second electrode down-leads to define a grid having a plurality of cells and a plurality of intersections; and

a plurality of electron emission units, wherein each of the plurality of electron emission units is positioned at one of the plurality of intersections and in at least two adjacent cells, and each of the plurality of electron emission units comprises:

a first electrode located on the insulating substrate;

a second electrode located on the insulating substrate and spaced from the first electrode, wherein the second electrode extends surrounding the first electrode; and

a plurality of electron emitters located on and electrically connected to at least one of the first electrode and the second electrode.

2. The field emission device of claim **1**, wherein the second electrode is L-shaped, U-shaped, C-shaped, semicircular-shaped or ring-shaped.

3. The field emission device of claim **2**, wherein the plurality of electron emitters is located on the second electrode and arranged to form a same shape as that of the second electrode.

4. The field emission device of claim **1**, wherein the second electrode is ring-shaped and located around the first electrode.

5. The field emission device of claim **4**, wherein each of the plurality of electron emission units is located in four adjacent cells.

6. The field emission device of claim **4**, wherein the plurality of electron emitters is located on the second electrode and comprises a plurality of ends arranged to form a ring-shape and pointing to the first electrode.

7. The field emission device of claim **4**, wherein the plurality of electron emitters is located on the first electrode and comprises a plurality of first ends arranged to form a ring-shape and pointing to the second electrode.

8. The field emission device of claim **7**, wherein the plurality of electron emitters comprises a plurality of carbon nanotube wires in parallel with each other.

9. The field emission device of claim **1**, wherein each of the plurality of electron emission units comprises a plurality of first electron emitters electrically connected to the first electrode, and a plurality of second electron emitters electrically connected to the second electrode.

10. The field emission device of claim **9**, wherein an alternating voltage is supplied to the first electrode and the second electrode.

11. A field emission display, comprising:

an insulating substrate;

a plurality of first electrode down-leads substantially parallel to each other and located on the insulating substrate;

a plurality of second electrode down-leads substantially parallel to each other and located on the insulating substrate, wherein the plurality of first electrode down-leads is set an angle relative to the plurality of second electrode down-leads to define a grid having a plurality of cells and a plurality of intersections; and

a plurality of pixel units, wherein each of the plurality of pixel units is positioned at one of the plurality of intersections and in at least two adjacent cells, and each of the plurality of pixel units comprises:

a cathode electrode located on the insulating substrate;

an electron emitter electrically connected to the cathode electrode;

an anode electrode located on the insulating substrate and spaced from the cathode electrode, wherein the anode electrode extends surrounding the cathode electrode; and

a phosphor layer located on the anode electrode and extending to surround the cathode electrode.

12. The field emission display of claim **11**, wherein the anode electrode is L-shaped, U-shaped, C-shaped, semicircular-shaped, or ring-shaped, and the phosphor layer has a same shape as that of the anode electrode.

13. The field emission display of claim **11**, wherein each of the plurality of electron emission units is located in four adjacent cells, and the anode electrode is ring-shaped and located around the cathode electrode.

14. The field emission display of claim **13**, wherein the electron emitter comprises a plurality of electron emission portions arranged to form a ring-shape and pointing to the phosphor layer.

15. The field emission display of claim **11**, wherein the anode electrode has a bearing surface inclined to the insulating substrate, and the phosphor layer is located on the bearing surface.

16. A field emission display, comprising:

an insulating substrate;

a plurality of first electrode down-leads substantially parallel to each other and located on the insulating substrate;

a plurality of second electrode down-leads substantially parallel to each other and located on the insulating substrate, wherein the plurality of first electrode down-leads is set an angle relative to the plurality of second electrode down-leads to define a grid having a plurality of cells and a plurality of intersections; and

a plurality of electron emission units, wherein each of the plurality of electron emission units is positioned at one of the plurality of intersections and in at least two adjacent cells, and each of the plurality of electron emission units comprises:

an anode electrode located on the insulating substrate;

a phosphor layer located on the anode electrode;

a cathode electrode located on the insulating substrate and spaced from the anode electrode, wherein the cathode electrode extends surrounding the anode electrode; and

a plurality of electron emitters electrically connected to the cathode electrode and arranged to surround the anode electrode.

17. The field emission display of claim **16**, wherein the cathode electrode is L-shaped, U-shaped, C-shaped, semicircular-shaped, or ring-shaped, and the plurality of electron emitters are arranged to form a same shape as that of the cathode electrode.

18. The field emission display of claim **16**, wherein each of the plurality of electron emission units is located in four adjacent cells, and the cathode electrode is ring-shaped and located around the anode electrode

19. The field emission display of claim **18**, wherein the plurality of electron emitters comprises a plurality of electron emission portions arranged to form a ring-shape and pointing to the phosphor layer.

20. The field emission display of claim **16**, wherein the anode electrode has a bearing surface inclined to the insulating substrate, and the phosphor layer is located on the bearing surface.

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